
Chipsmall
深圳市津利帝科技有限公司
Geelead Technology Limited
Chipsmall
采购部

SK12-SK110

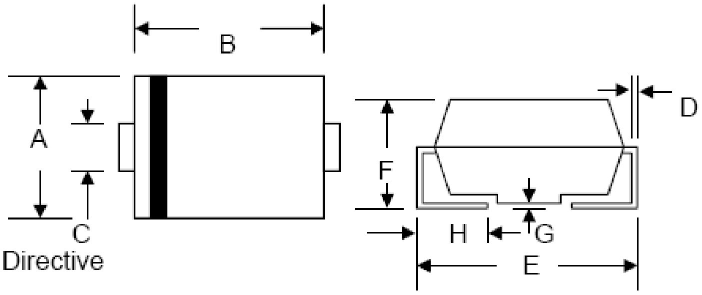
1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Technical Data
Data Sheet N0930, Rev. A

Green products

Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 30A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- Green Products in Compliance with the RoHS Directive
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



SMB/DO-214AA				
Dim	**Min**	**Max**	**Min**	**Max**
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.91	2.11	0.075	0.083
D	0.15	0.31	0.006	0.012
E	5.08	5.59	0.200	0.220
F	2.13	2.44	0.084	0.096
G	0.05	0.20	0.002	0.008
H	0.76	1.27	0.030	0.050
	In mm		**In inch**	

Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

Marking Diagram:

Where XXXXX is YYWWL

SK12	= Part Name
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SK12-SK110	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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Maximum Ratings and Electrical characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	SK12	SK13	SK14	SK15	SK16	SK18	SK19	SK110	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	20	30	40	50	60	80	90	100	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @T_L= 75°C	I_O	1.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30								A
Forward Voltage @ I_O= 1.0 A	V_F	0.55			0.70		0.85			V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	0.5 20								mA
Typical Thermal Resistance Junction to Ambient (Note 1)	$R_{\theta JA}$	95								K/W
Operating Temperature Range	T_J	-55 to +125								°C
Storage Temperature Range	T_{STG}	-55 to +150								°C

Note: 1. mounted on P.C. Board with 0.5mm^2 copper pad areas.

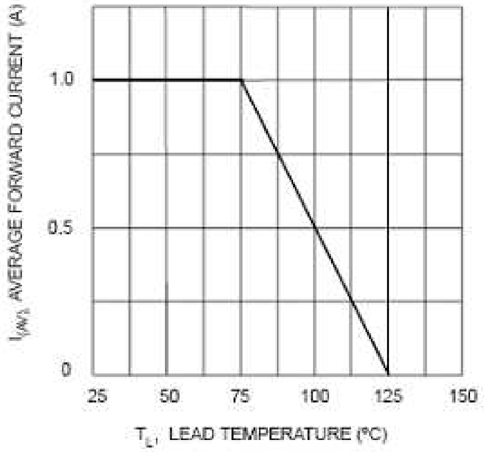

Fig. 1 Forward Current Derating Curve

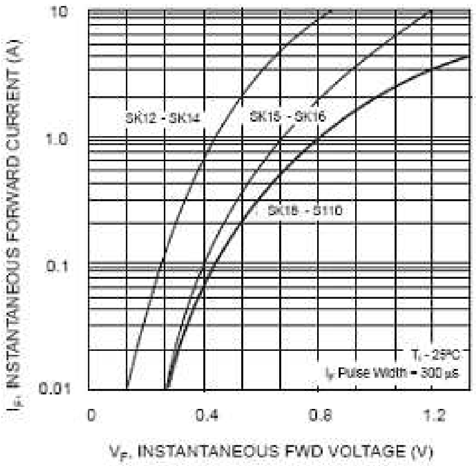

Fig. 2 Typ. Forward Characteristics

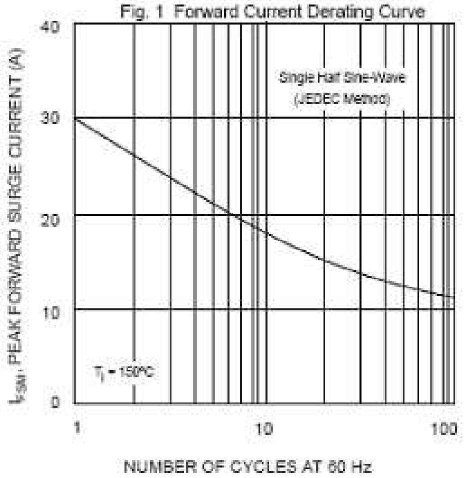

Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

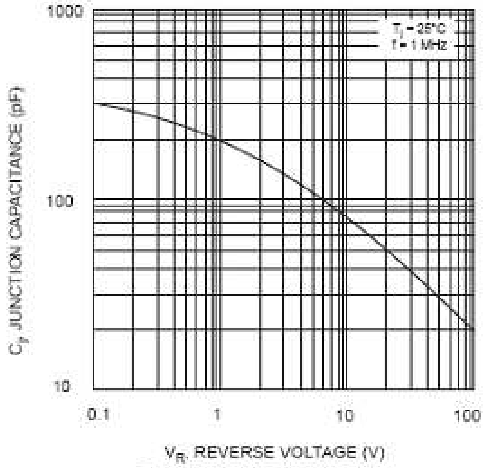

Fig. 4 Typical Junction Capacitance

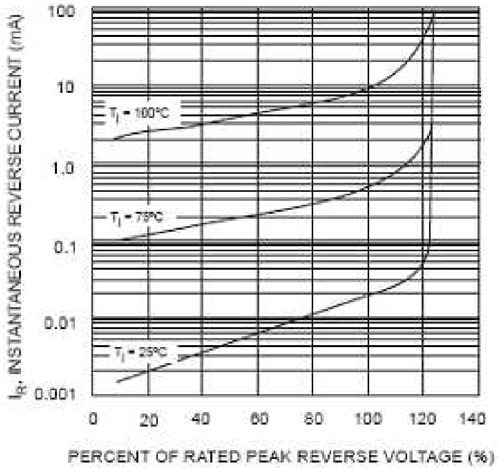

Fig. 5 Typical Reverse Characteristics

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